

L Number	Hits	Search Text	DB	Time stamp
1	0	vertical adj transistor and reverse adj "T" and (trench or via) and gate	USPAT; EPO; JPO; DERWENT	2004/06/25 09:37
2	0	reverse adj "T" and (trench or via) and gate and isolation adj layer	USPAT; EPO; JPO; DERWENT	2004/06/25 09:38
3	0	reverse adj "T-shaped" and (trench or via) and gate and isolation adj layer	USPAT; EPO; JPO; DERWENT	2004/06/25 09:38
4	0	reverse adj T-shaped and (trench or via) and gate and isolation adj layer	USPAT; EPO; JPO; DERWENT	2004/06/25 09:38
5	0	reverse adj T adj shaped and (trench or via) and gate and isolation adj layer	USPAT; EPO; JPO; DERWENT	2004/06/25 09:42
6	0	reverse and (trench or via) and gate and isolation adj layer and trench adj top adj oxide	USPAT; EPO; JPO; DERWENT	2004/06/25 09:43
7	5	reverse and (trench or via) and gate and isolation and trench adj top adj oxide	USPAT; EPO; JPO; DERWENT	2004/06/25 09:43